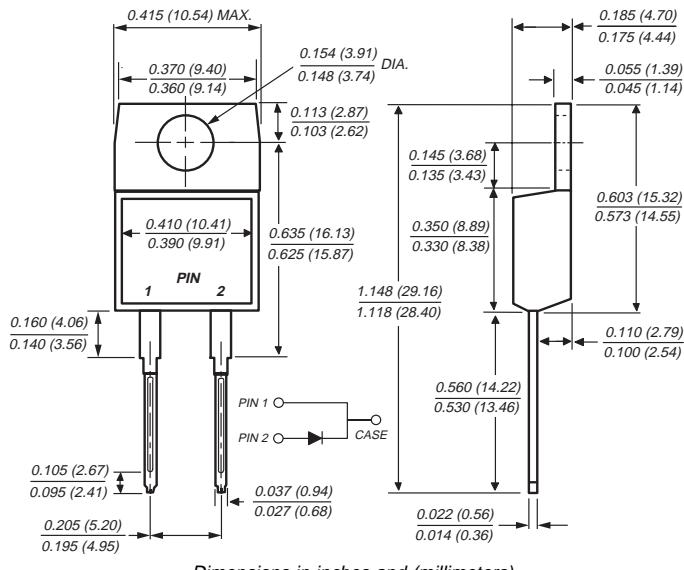

**TO-220AC**


## Ultrafast Plastic Rectifier

**Reverse Voltage** 50 to 200V

**Forward Current** 8.0A

### Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated chip junction
- Low power loss
- Low leakage current
- High surge capability
- Superfast recovery time for high efficiency
- High temperature soldering guaranteed: 250°C, 0.16" (4.06mm) from case for 10 seconds

### Mechanical Data

**Case:** JEDEC TO-220AC molded plastic body over passivated chips

**Terminals:** Lead solderable per MIL-STD-750, Method 2026

**Polarity:** As marked

**Mounting Position:** Any

**Mounting Torque:** 10 in-lbs max.

**Weight:** 0.064 ounce, 1.81 grams

### Maximum Ratings and Thermal Characteristics ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	GI1401	GI1402	GI1403	GI1404	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	V
Maximum average forward rectified current at $T_C = 125^\circ\text{C}$	I <sub>F(AV)</sub>			8.0		A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>			125		A
Typical thermal resistance (Note 1) (Note 2)	R <sub>θJA</sub> R <sub>θJC</sub>			15 2.2		°C/W
Operating and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>			-65 to +150		°C

### Electrical Characteristics ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

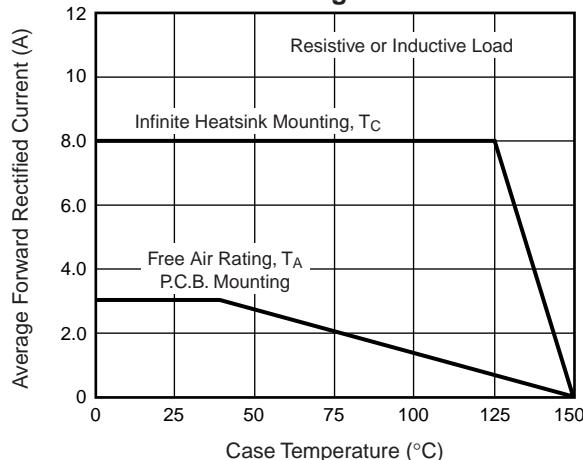
Parameter	Symbol	GI1401	GI1402	GI1403	GI1404	Unit
Maximum instantaneous forward voltage at	I <sub>F</sub> = 4A, T <sub>J</sub> = 25°C I <sub>F</sub> = 8A, T <sub>J</sub> = 25°C I <sub>F</sub> = 4A, T <sub>J</sub> = 100°C I <sub>F</sub> = 8A, T <sub>J</sub> = 100°C	V <sub>F</sub>		0.900 0.975 0.800 0.895		V
Maximum DC reverse current at rated DC blocking voltage at	T <sub>C</sub> = 25°C T <sub>C</sub> = 100°C	I <sub>R</sub>		5.0 150		μA
Maximum reverse recovery time at	t <sub>rr</sub>			35		ns
I <sub>F</sub> = 0.5A, I <sub>R</sub> = 1.0A, I <sub>rr</sub> = 0.25A						
Typical junction capacitance at 4V, 1MHz	C <sub>J</sub>			85		pF

**Notes:** (1) Thermal resistance from junction to ambient in free air, no heatsink

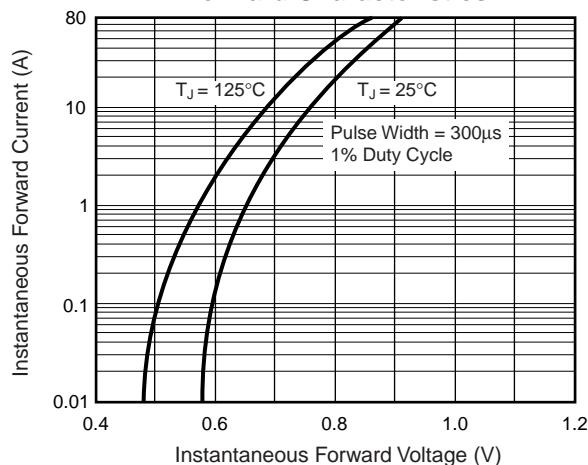
(2) Thermal resistance from junction to case and ambient mounted on heatsink

### Ratings and Characteristic Curves ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

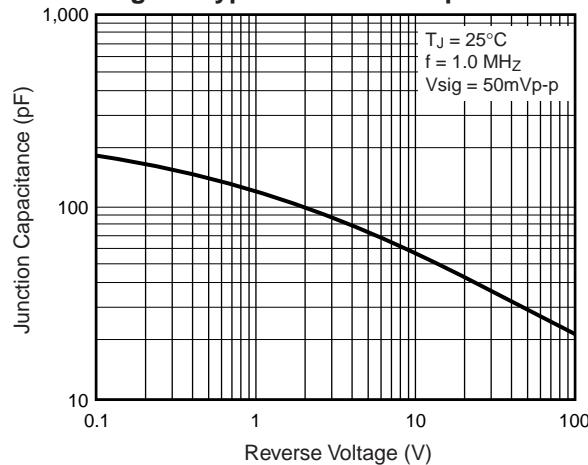
**Fig. 1 – Maximum Forward Current Derating Curve**



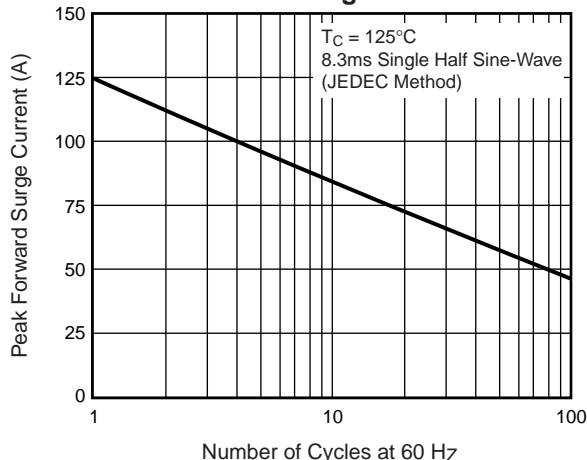
**Fig. 3 – Typical Instantaneous Forward Characteristics**



**Fig. 5 – Typical Junction Capacitance**



**Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current**



**Fig. 4 – Typical Reverse Leakage Characteristics**

